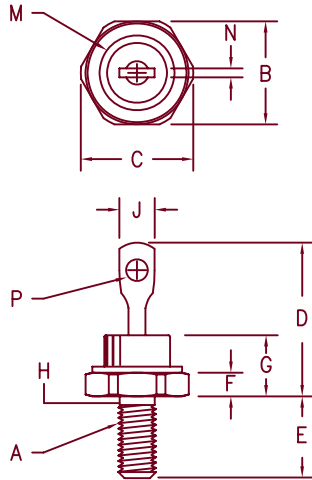


25 Amp Schottky Rectifiers

1N5829 — 1N5831



- Notes:
- 10-32 UNF3A threads
 - Full threads within 2 1/2 threads Standard Polarity: Stud is Cathode

Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	----	----	----	----	1
B	.424	.437	10.77	11.10	
C	----	.505	----	12.82	
D	.600	.800	15.24	20.32	
E	.422	.453	10.72	11.50	
F	.075	.175	1.91	4.44	
G	----	.405	----	10.29	
H	.163	.189	4.15	4.80	2
J	----	.250	----	6.35	
M	----	.350	----	8.89	Dia.
N	.020	.065	.510	1.65	
P	.060	.100	1.53	2.54	Dia.

D0203AA (D04)

Microsemi
Catalog Number

1N5829
1N5830
1N5831

Working Peak
Reverse Voltage

20V
30V
40V

Repetitive Peak
Reverse Voltage

20V
30V
40V

- Schottky Barrier Rectifier
- Guard ring protection
- Low forward voltage drop
- 25 Amperes
- 125°C Junction Temperature
- VRRM 20 to 40 volts

Electrical Characteristics

		1N5829	1N5830	1N5831	
Average forward current	I F(AV)	25A	25A	25A	T _C = 97°C, square wave, R _{θJC} = 1.75°C/W
Maximum surge current	I FSM	800A	800A	800A	8.3ms, half sine, T _J = 125°C
Max peak forward voltage	V FM	.360V	.370V	.380V	I FM = 10A: T _J = 25°C*
Max peak forward voltage	V FM	.440V	.460V	.480V	I FM = 25A: T _J = 25°C*
Max peak forward voltage	V FM	.720V	.770V	.820V	I FM = 78.5A: T _J = 25°C*
Max peak reverse current	I RM	150mA	150mA	150mA	V RRM, T _J = 100°C
Max peak reverse current	I RM	3.0mA	3.0mA	3.0mA	V RRM, T _J = 25°C
Typical junction capacitance	C J	1650pF	1650pF	1650pF	T _J = 25°C, V R = 5V, f = 1MHz

*Pulse test: Pulse width 300 μsec, Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range	T STG	-65°C to 125°C
Operating junction temp range	T J	-65°C to 125°C
Maximum thermal resistance	R θJC	1.75°C/W junction to case
Typical thermal resistance	R θJS	0.5°C/W junction to sink
Mounting torque		15 inch pounds maximum
Weight		6 grams (.02 ounces) typical



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05-09-07 Rev. 3

1N5829–1N5831

Figure 1
Typical Forward Characteristics

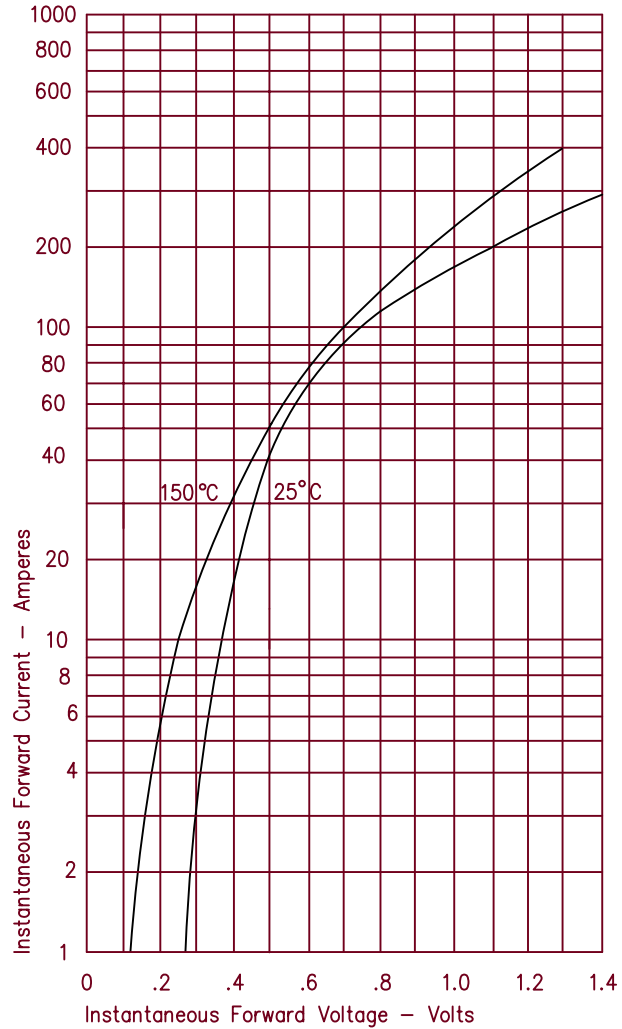


Figure 3
Typical Junction Capacitance

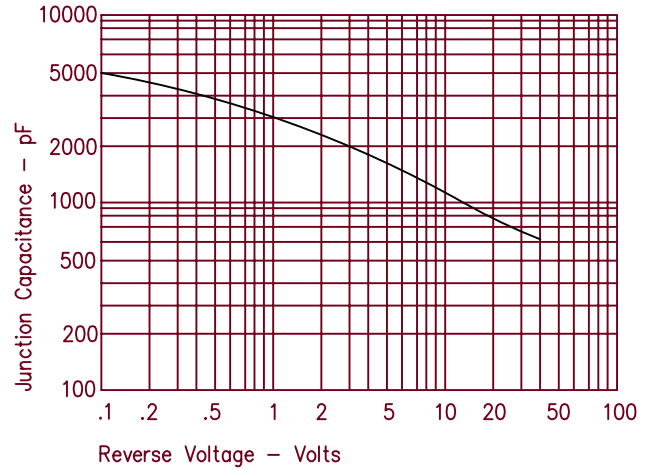


Figure 4
Maximum Forward Power Dissipation

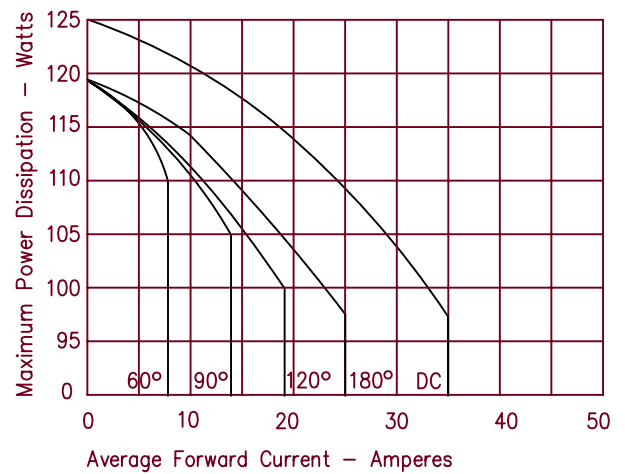


Figure 2
Typical Reverse Characteristics

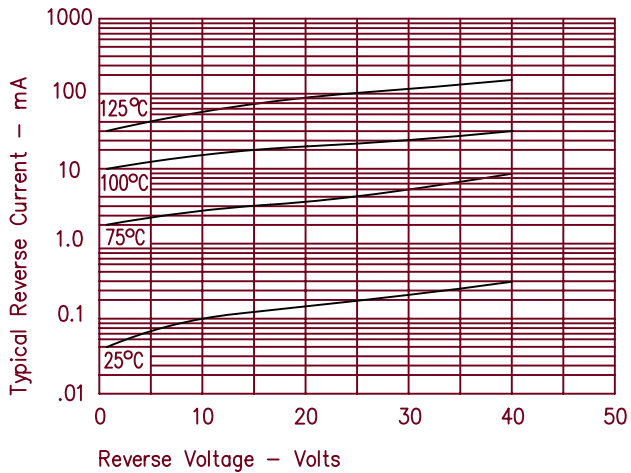


Figure 5
Maximum Forward Power Dissipation

